# Light modulation photo IC \$4282-51, \$6809, \$6846, \$6986, \$7136/-10, \$10053



Fewer detection errors even under disturbance background light

These light modulation photo ICs were developed for optical synchronous detection under disturbance background light. A photodiode, preamplifier, comparator, oscillator, LED driver and signal processing circuit, etc. are all integrated on a monolithic photo IC chip. Optical synchronous type photoreflectors and photointerrupters, which less susceptible to disturbance background light, can be easily configured by just connecting an external LED to this photo IC. Our unique circuit design achieves an allowable background light level of 10000 *lx* Typ. (S4282-51, S6986, S10053) and a minimum detection level of 0.2 µW/mm² Typ. (S6809, S6846, S7136/-10).

#### **Features**

- Large allowable background light level S4282-51, S6986, S10053: 10000 lx Typ. S6809, S6846, S7136/-10: 3000 lx Typ.
- Minimum detection level S4282-51, S6986, S10053: 0.7 μW/mm² Typ. S6809, S6846, S7136/-10: 0.2 μW/mm² Typ.
- Digital output (Output appears "L" by light input.)
- Small hysteresis (S6809)
- Small SMD package (S10053)

# Applications

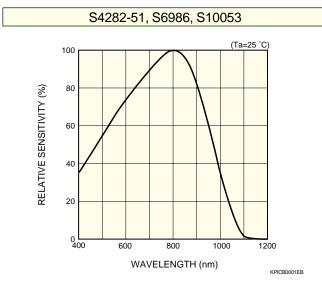
- Paper detection in office machine (copiers, fax machines, etc.)
- Optical switch

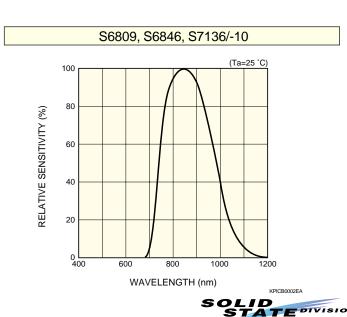
■ Absolute maximum ratings (Ta=25 °C)

= 7 to ordite maximum ratings (ra 20 °)											
Parameter	Symbol	S4282-51, S6986, S10053	S6809, S6846, S7136/-10	Unit							
Supply voltage	Vcc	-0.5 t	V								
Output voltage	Vo	-0.5 t	V								
Output current	lo	5	mA								
Cathode output voltage	Vcath	-0.5 t	V								
Cathode output current	Icath		70	mA							
Power dissipation *1	Р	25	mW								
Operating temperature	Topr	-25 to	°C								
Storage temperature	Tstg	-40 to	°C								

<sup>\*1:</sup> Derate power dissipation at a rate of 3.3 mW/°C above Ta=25 °C

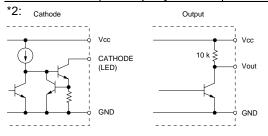
### ■ Spectral response (typical example)

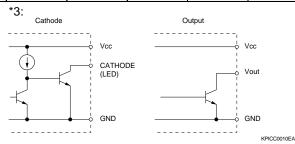




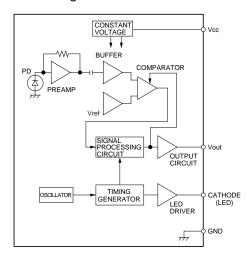
■ Electrical and optical characteristics (Ta=25 °C, Vcc=5 V)

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				S4282-51, S6986, S10053		S6809, S6846, S7136 /-10				
Parameter		Symbol	Condition	Output: built-in pull-up resistor *2		Output: open collector *3			Unit	
				Cathode: constant current drive		Cathode: open collector drive				
				Min.	Тур.	Max.	Min.	Тур.	Max.	
Supply voltage		Vcc		4.5	-	16	4.5	-	16	V
Current consumption		Icc	Vo, LED terminals open	-	4	11	-	4	11	mA
Outpo	Low level output voltage	Vol	IoL=16 mA	ı	0.2	0.4	-	0.2	0.4	V
	High level			4.9				V		
		Vон	4.7 kΩ between Vcc and Vo				4.9	-	-	V
Cathode	Low level output voltage	Vcath	lcath=40 mA				-	-	0.8	V
	Low level output current	Icath	Vcath=1.2 V	15 35 60						mA
	Pulse cycle	Тр		65	130	220	65	130	220	μs
	Pulse width	Tw		4	8	13.7	4	8	13.7	μs
H→L Threshold light level		EHL	λ=940 nm No background light	-	0.7	2	-	0.2	1.0	μW/mm²
,							0.45	0.65	0.95	
Hysteresis		-		0.45	0.65	0.95	0.65 (S6809)	0.8 (S6809)	0.95 (S6809)	-
Frequency response		f		0.5	1.25	-	0.5	1.25	-	kHz
Allowable background light level		Ex	Signal light: $5 \mu W / m m^2$ $\lambda p = 940 \text{ nm}$ Background light: "A" light source	5000	10000	-	2000	3000	-	lx





## ■ Block diagram and internal functions



TRUTH TABLE

INPUT OUTPUT LEVEL

LIGHT ON LOW

LIGHT OFF HIGH

(a) Oscillator and timing signal generator

The oscillator produces a reference oscillation output by charging and discharging the built-in capacitor with constant current. The oscillation output is fed to the timing signal generator, which then creates LED drive pulses and various timing pulses for digital signal processing.

(b) LED driver circuit

This circuit drives an external LED using the LED drive pulses created by the timing signal generator. The duty cycle is 1/16.

(c) Photodiode and preamplifier circuit

The photodiode is formed on the same monolithic chip. A photocurrent generated in the photodiode is converted to a voltage by a preamplifier circuit. The preamplifier circuit uses an AC amplifier to expand the dynamic range versus DC or low-frequency background light, without impairing signal detection sensitivity.

- (d) Capacitive coupling, buffer amplifier and reference voltage generator Capacitive coupling removes low-frequency noise and also cancels the DC offset in the preamplifier. The buffer amplifier boosts the signal up to the comparator level, and the reference voltage generator produces a comparator level voltage.
- (e) Comparator circuit

The comparator circuit has a hysteresis function to prevent chattering caused by small fluctuations in the input light.

(f) Signal processing circuit

The signal processing circuit consists of a gate circuit and digital integrator circuit. The gate circuit discriminates input pulses during synchronous detection, to prevent operational errors caused by asynchronous background light. Background light which is synchronized with the signal detection timing cannot be eliminated by the gate circuit, but is canceled out by the digital integrator circuit at the latter stage.

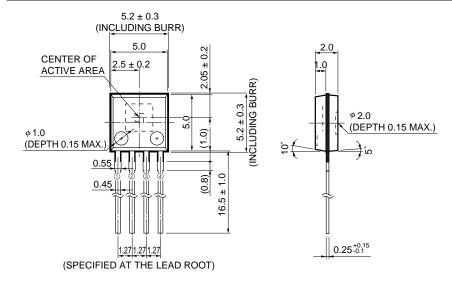
(g) Output circuit

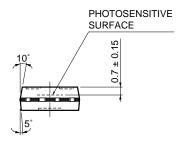
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This circuit serves as an output buffer for the signal processing circuit and outputs the signal to an external circuit.

## ■ Dimensional outlines (unit: mm)

## S6809, S6846, S6986



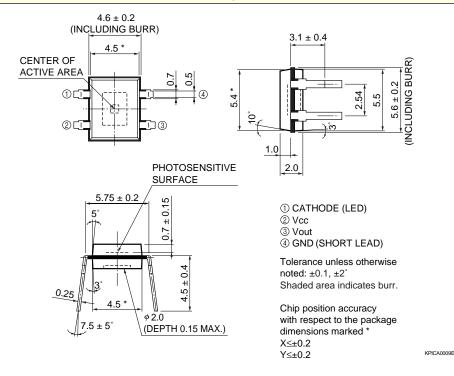


- ① Vout
- ② GND
- ③ CATHODE (LED)
- 4 Vcc

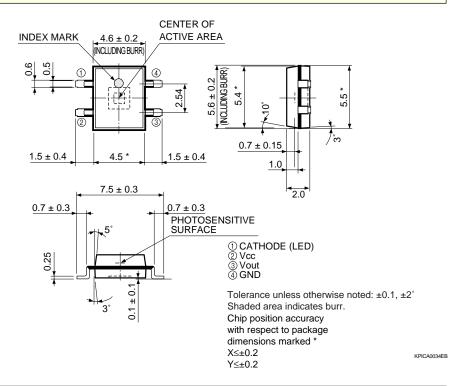
Tolerance unless otherwise noted: ±0.1, ±2°
Shaded area indicates burr.
Values in parentheses are not guaranteed, but for reference.

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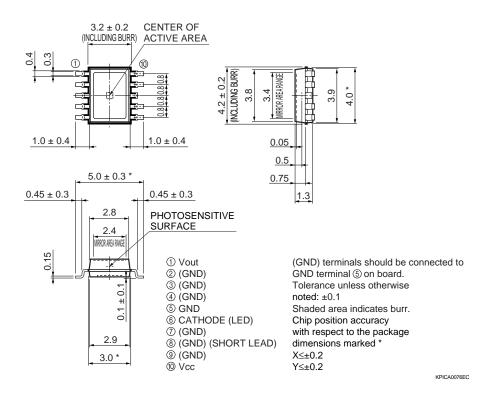
## S4282-51, S7136



#### S7136-10



#### S10053



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